



HIGHLAND TECHNOLOGY

Statement of Volatility

The following comprises the volatile and non-volatile memories on the P900 3-Phase Power Source and PM Alternator Simulator module.

Volatile

SRAM	132 kB	Processor memory
DRAM	4 GB	FPGA memory

Non-Volatile

NOR FLASH	128 MB	Firmware. Field writable. Lock Switch protected to deny writing to FLASH. Factory Calibration. Password protected from user access.
-----------	--------	----------------------------------------------------------------------------------------------------------------------------------------